

## GaAs SPST Absorptive Switch with ASIC Driver, DC-3.0 GHz

Rev. V7

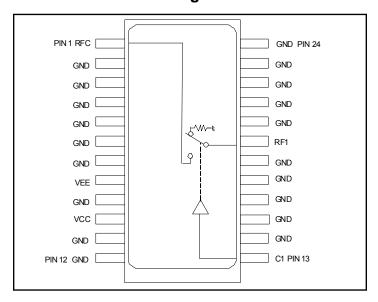
#### **Features**

- Typical Isolation: 42 dB (2,000 MHz)
- Typical Insertion Loss: 1.8 dB (2,000 MHz)
- Integral ASIC TTL/CMOS Driver
- Low DC Power Consumption
- 50 Ohm Nominal Impedance
- Tape and Reel Packaging Available
- Test Boards Available
- SOW-24 Package

#### **Description**

M/A-COM's SW65-0014 is a GaAs MMIC absorptive SPST switch with an integral silicon ASIC driver. This device is in a 24-lead plastic package. This switch offers excellent broadband performance and repeatability from DC to 3 GHz, while maintaining low DC power dissipation. The SW65-0014 is ideally suited for wireless infrastructure applications. Also available in ceramic package with improved performance.

#### **Functional Block Diagram**



## **Ordering Information**

Part Number	Package
SW65-0014	Bulk Packaging
SW65-0014TR	1000 piece reel
SW65-0014-TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

## **Pin Configuration**

Pin No.	Function	Pin No.	Function
1	RFc	13	C1
2	GND	14	GND
3	GND	15	GND
4	GND	16	GND
5	GND	17	GND
6	GND	18	GND
7	GND	19	RF1
8	$V_{EE}$	20	GND
9	GND	21	GND
10	V <sub>CC</sub>	22	GND
11	GND	23	GND
12	GND	24	GND

<sup>•</sup> India Tel: +91.80.4155721 · China Tel: +86.21.2407.1588



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## Electrical Specifications: $T_A = 25$ °C, $Z_0 = 50\Omega$

Parameter	Test Conditions	Units	Min	Тур	Max
Insertion Loss	DC - 3.0 GHz	dB	_	1.8	2.2
Isolation (All arms off)	DC - 3.0 GHz	dB	35	42	_
VSWR	DC - 3.0 GHz On Off	_	_	1.6:1 2.0:1	2.1:1 2.1:1
T <sub>rise</sub> T <sub>fall</sub> T <sub>on</sub> T <sub>off</sub> Transients	10%/90%, 90%/10% <sup>1</sup> 50% TTL to 90%/10% RF In-band (peak to peak)	ns ns mV		15 50 50	50 150 150
1 dB Compression	.05 GHz .5 - 3.0 GHz	dBm dBm		+20 +27	_
Input IP3	Two tone inputs 0.05 GHz Up to +5 dBm 0.5 - 3.0 GHz	dBm dBm		+35 +46	_
Vcc	<del>-</del>	V	+4.5	+5.0	+5.5
VEE	<del>-</del>	V	-8.0	-5.0	-4.75
V <sub>IL</sub> V <sub>IH</sub>	LOW-level input voltage HIGH-level input voltage	V	0.0 2.0	_	0.8 5.0
lin (Input Leakage Current)	Vin = V <sub>CC</sub> or GND	uA	-1.0	_	1.0
Icc (Quiescent Supply Current)	Vcntrl = V <sub>CC</sub> or GND	uA	_	250	400
Δlcc (Additional Supply Current Per TTL Input Pin)	V <sub>CC</sub> = Max, Vcntrl = V <sub>CC</sub> - 2.1 V	mA	_	_	1.0
lee	VEE min to max, Vin = $V_{IL}$ or $V_{IH}$	mA	-1.0	-0.2	_

<sup>1.</sup> Decoupling capacitors (.01 µF) are required on the power supply lines.

## Absolute Maximum Ratings <sup>2,3</sup>

Parameter	Absolute Maximum
Max. Input Power 0.05 GHz 0.5 - 3.0 GHz <sup>4</sup>	+27 dBm +34 dBm
V <sub>CC</sub>	-0.5V ≤ V <sub>CC</sub> ≤ +7.0V
V <sub>EE</sub>	-8.5V ≤ V <sub>EE</sub> ≤ +0.5V
V <sub>CC</sub> - V <sub>EE</sub>	$-0.5V \le V_{CC} - V_{EE} \le 14.5V$
Vin <sup>5</sup>	-0.5V ≤ Vin ≤ V <sub>CC</sub> + 0.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

- 2. Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.
- 4. When the RF input is applied to the terminated port, the absolute maximum power is +30 dBm.
- Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

## **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

#### **Truth Table**

TTL Control Input	RF Common To:
C1	RF1
1	On
0	Off

- North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400
- India Tel: +91.80.4155721
  China Tel: +86.21.2407.1588
  Visit www.macomtech.com for additional data sheets and product information.

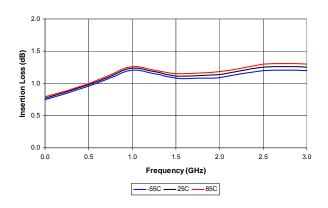


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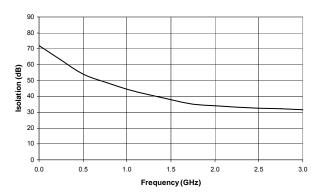
Rev. V7

## **Typical Performance Curves**

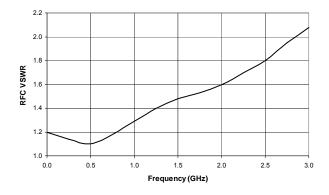
#### Insertion Loss vs. Frequency



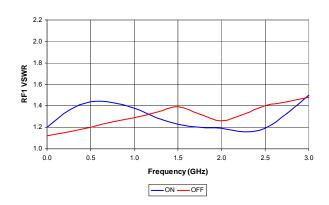
#### Isolation Loss vs. Frequency



#### RFC VSWR vs. Frequency



#### RF1 VSWR vs. Frequency



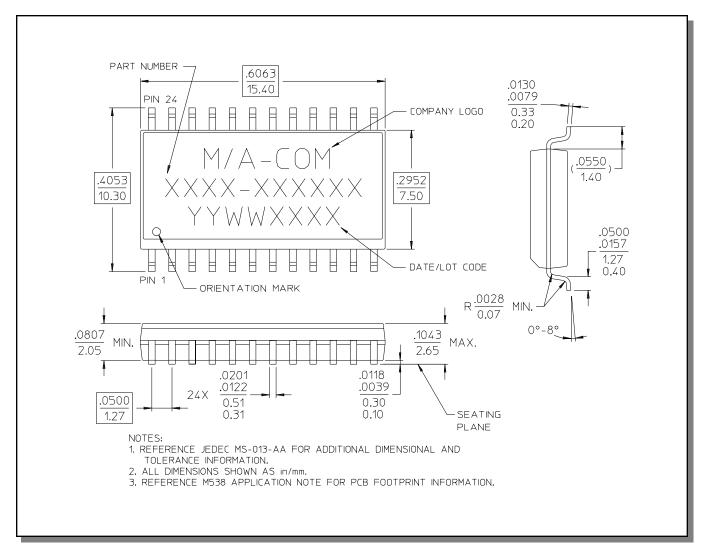
## SW65-0014



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#### SOW-24<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations.